

2N7002K, 2V7002K

Small Signal MOSFET

60 V, 380 mA, Single, N-Channel, SOT-23

Features

- ESD Protected
- Low $R_{DS(on)}$
- Surface Mount Package
- 2V Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- Low Side Load Switch
- Level Shift Circuits
- DC-DC Converter
- Portable Applications i.e. DSC, PDA, Cell Phone, etc.

MAXIMUM RATINGS ($T_J = 25^\circ\text{C}$ unless otherwise stated)

| Rating | Symbol | Value | Unit |
|---|----------------|---------------------------------|------------------|
| Drain-to-Source Voltage | V_{DS} | 60 | V |
| Gate-to-Source Voltage | V_{GS} | ± 20 | V |
| Drain Current (Note 1) Steady State 1 sq in Pad | I_D | $T_A = 25^\circ\text{C}$ 380 | mA |
| | | $T_A = 85^\circ\text{C}$ 270 | |
| Drain Current (Note 2) Steady State Minimum Pad | I_D | $T_A = 25^\circ\text{C}$ 320 | mA |
| | | $T_A = 85^\circ\text{C}$ 230 | |
| Power Dissipation Steady State 1 sq in Pad Steady State Minimum Pad | P_D | 420 | mW |
| | | 300 | |
| Pulsed Drain Current ($t_p = 10 \mu\text{s}$) | I_{DM} | 1.5 | A |
| Operating Junction and Storage Temperature Range | T_J, T_{STG} | -55 to +150 | $^\circ\text{C}$ |
| Source Current (Body Diode) | I_S | 300 | mA |
| Lead Temperature for Soldering Purposes (1/8" from case for 10 s) | T_L | 260 | $^\circ\text{C}$ |
| Gate-Source ESD Rating (HBM, Method 3015) | ESD | 2000 | V |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Surface-mounted on FR4 board using 1 sq in pad size with 1 oz Cu.
2. Surface-mounted on FR4 board using 0.08 sq in pad size with 1 oz Cu.

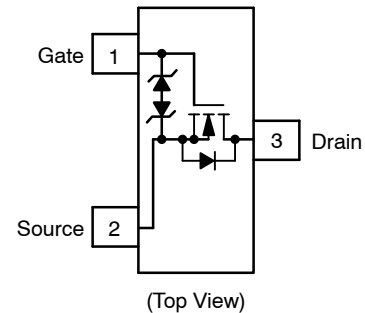


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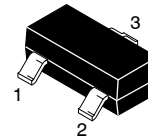
<http://onsemi.com>

| $V_{(BR)DSS}$ | $R_{DS(on)}$ MAX | I_D MAX |
|---------------|----------------------|-----------|
| 60 V | 1.6 Ω @ 10 V | 380 mA |
| | 2.5 Ω @ 4.5 V | |

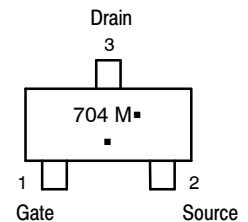
SIMPLIFIED SCHEMATIC



MARKING DIAGRAM & PIN ASSIGNMENT



SOT-23
CASE 318
STYLE 21



- 704 = Specific Device Code*
- M = Date Code*
- = Pb-Free Package

(Note: Microdot may be in either location)
*Specific Device Code, Date Code or overbar orientation and/or location may vary depending upon manufacturing location. This is a representation only and actual devices may not match this drawing exactly.

ORDERING INFORMATION

| Device | Package | Shipping† |
|------------|---------------------|--------------------|
| 2N7002KT1G | SOT-23 (Pb-Free) | 3000 / Tape & Reel |
| 2V7002KT1G | SOT-23 (Pb-Free) | 3000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|---|-----------------|-----|------|
| Junction-to-Ambient – Steady State (Note 3) | $R_{\theta JA}$ | 300 | °C/W |
| Junction-to-Ambient – $t \leq 5$ s (Note 3) | | 92 | |
| Junction-to-Ambient – Steady State (Note 4) | | 417 | |
| Junction-to-Ambient – $t \leq 5$ s (Note 4) | | 154 | |

3. Surface-mounted on FR4 board using 1 sq in pad size with 1 oz Cu.

4. Surface-mounted on FR4 board using 0.08 sq in pad size with 1 oz Cu.

ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$ unless otherwise specified)

| Parameter | Symbol | Test Condition | Min | Typ | Max | Unit |
|-----------|--------|----------------|-----|-----|-----|------|
|-----------|--------|----------------|-----|-----|-----|------|

OFF CHARACTERISTICS

| | | | | | | |
|---|-------------------|--------------------------------------|---------------------------|----|----------|---------|
| Drain-to-Source Breakdown Voltage | $V_{(BR)DSS}$ | $V_{GS} = 0$ V, $I_D = 250$ μ A | 60 | | | V |
| Drain-to-Source Breakdown Voltage Temperature Coefficient | $V_{(BR)DSS}/T_J$ | | | 71 | | mV/°C |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{GS} = 0$ V, $V_{DS} = 60$ V | $T_J = 25^\circ\text{C}$ | | 1 | μ A |
| | | | $T_J = 125^\circ\text{C}$ | | 10 | |
| | | $V_{GS} = 0$ V, $V_{DS} = 50$ V | $T_J = 25^\circ\text{C}$ | | 100 | nA |
| Gate-to-Source Leakage Current | I_{GSS} | $V_{DS} = 0$ V, $V_{GS} = \pm 20$ V | | | ± 10 | μ A |
| | | $V_{DS} = 0$ V, $V_{GS} = \pm 10$ V | | | 450 | nA |
| | | $V_{DS} = 0$ V, $V_{GS} = \pm 5.0$ V | | | 150 | nA |

ON CHARACTERISTICS (Note 5)

| | | | | | | |
|--|------------------|---|-----|------|-----|----------|
| Gate Threshold Voltage | $V_{GS(TH)}$ | $V_{GS} = V_{DS}$, $I_D = 250$ μ A | 1.0 | | 2.3 | V |
| Negative Threshold Temperature Coefficient | $V_{GS(TH)}/T_J$ | | | 4.0 | | mV/°C |
| Drain-to-Source On Resistance | $R_{DS(on)}$ | $V_{GS} = 10$ V, $I_D = 500$ mA | | 1.19 | 1.6 | Ω |
| | | $V_{GS} = 4.5$ V, $I_D = 200$ mA | | 1.33 | 2.5 | |
| Forward Transconductance | g_{FS} | $V_{DS} = 5$ V, $I_D = 200$ mA | | 530 | | mS |

CHARGES AND CAPACITANCES

| | | | | | | |
|------------------------------|--------------|---|--|------|--|---------|
| Input Capacitance | C_{ISS} | $V_{GS} = 0$ V, $f = 1$ MHz, $V_{DS} = 20$ V | | 24.5 | | μ F |
| Output Capacitance | C_{OSS} | | | 4.2 | | |
| Reverse Transfer Capacitance | C_{RSS} | | | 2.2 | | |
| Total Gate Charge | $Q_{G(TOT)}$ | $V_{GS} = 4.5$ V, $V_{DS} = 10$ V; $I_D = 200$ mA | | 0.7 | | nC |
| Threshold Gate Charge | $Q_{G(TH)}$ | | | 0.1 | | |
| Gate-to-Source Charge | Q_{GS} | | | 0.3 | | |
| Gate-to-Drain Charge | Q_{GD} | | | 0.1 | | |

SWITCHING CHARACTERISTICS, $V_{GS} = V$ (Note 6)

| | | | | | | |
|---------------------|--------------|---|--|------|--|----|
| Turn-On Delay Time | $t_{d(ON)}$ | $V_{GS} = 10$ V, $V_{DD} = 25$ V, $I_D = 500$ mA, $R_G = 25$ Ω | | 12.2 | | ns |
| Rise Time | t_r | | | 9.0 | | |
| Turn-Off Delay Time | $t_{d(OFF)}$ | | | 55.8 | | |
| Fall Time | t_f | | | 29 | | |

DRAIN-SOURCE DIODE CHARACTERISTICS

| | | | | | | | |
|-----------------------|----------|--------------------------------|--------------------------|--|-----|-----|---|
| Forward Diode Voltage | V_{SD} | $V_{GS} = 0$ V, $I_S = 200$ mA | $T_J = 25^\circ\text{C}$ | | 0.8 | 1.2 | V |
| | | | $T_J = 85^\circ\text{C}$ | | 0.7 | | |

5. Pulse Test: pulse width ≤ 300 μ s, duty cycle $\leq 2\%$

6. Switching characteristics are independent of operating junction temperatures

TYPICAL CHARACTERISTICS

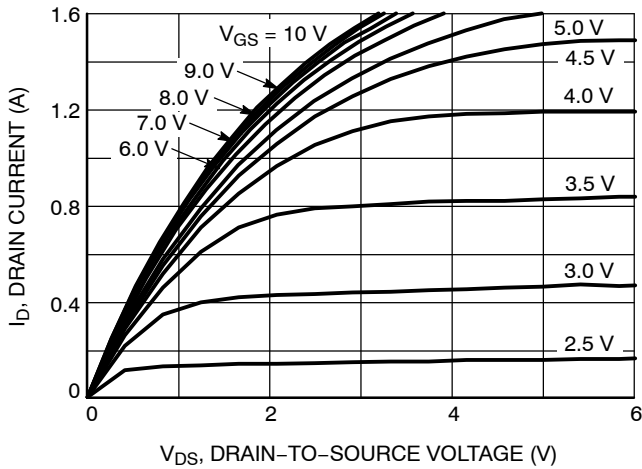


Figure 1. On-Region Characteristics

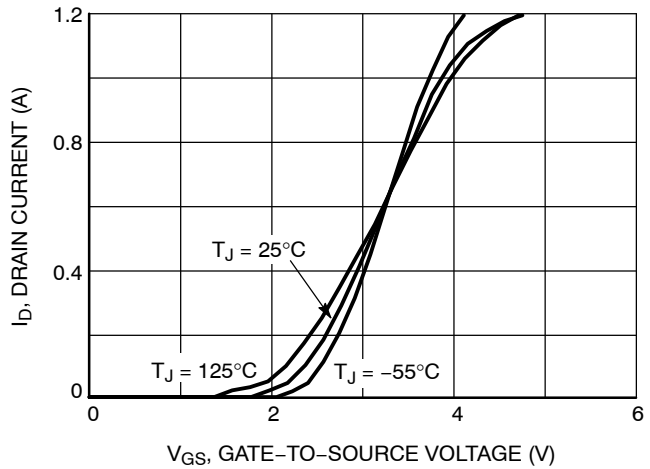


Figure 2. Transfer Characteristics

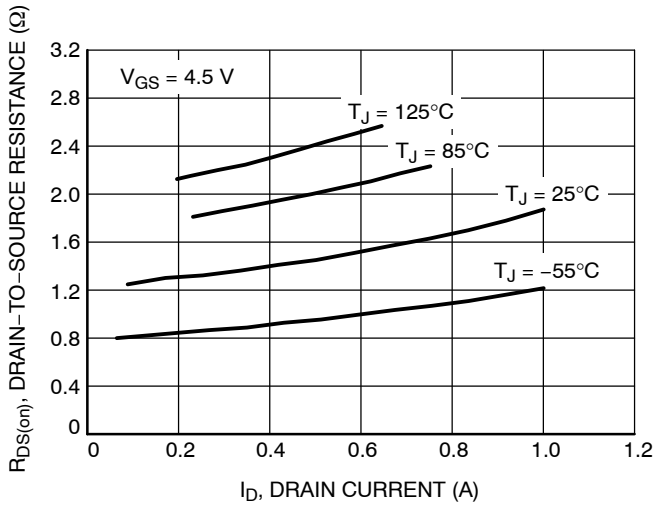


Figure 3. On-Resistance vs. Drain Current and Temperature

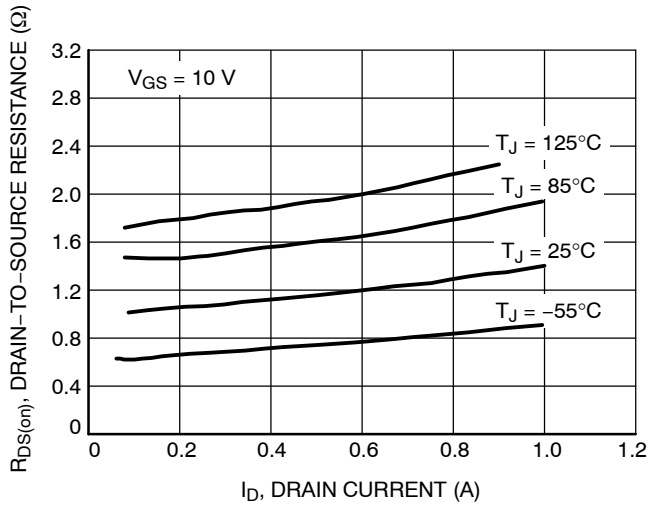


Figure 4. On-Resistance vs. Drain Current and Temperature

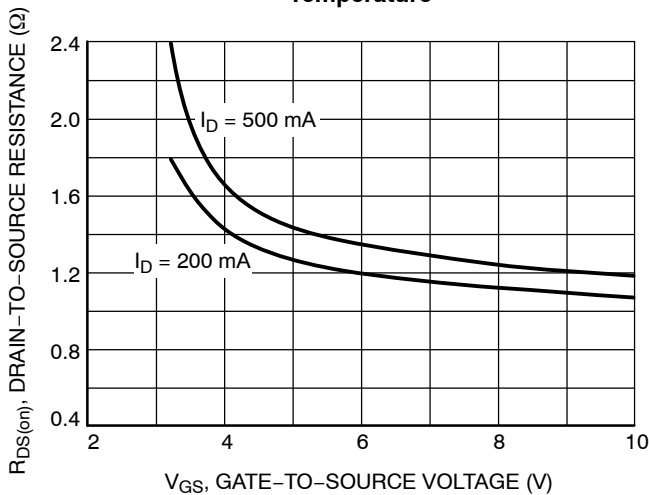


Figure 5. On-Resistance vs. Gate-to-Source Voltage

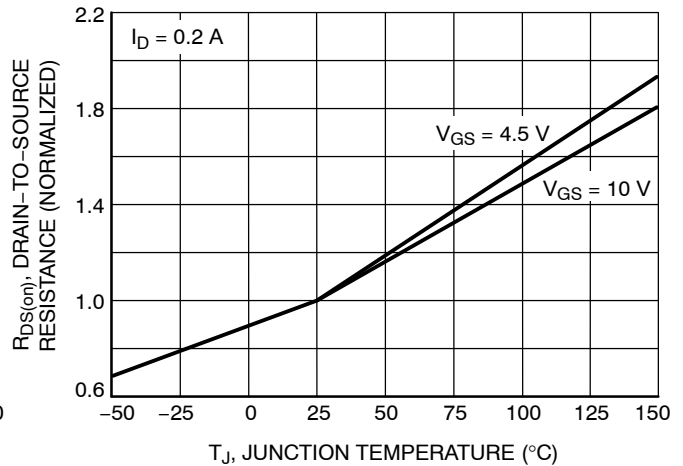


Figure 6. On-Resistance Variation with Temperature

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TYPICAL CHARACTERISTICS

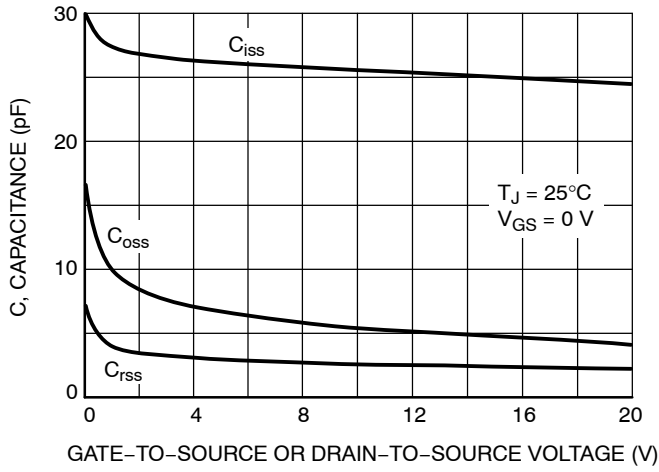


Figure 7. Capacitance Variation

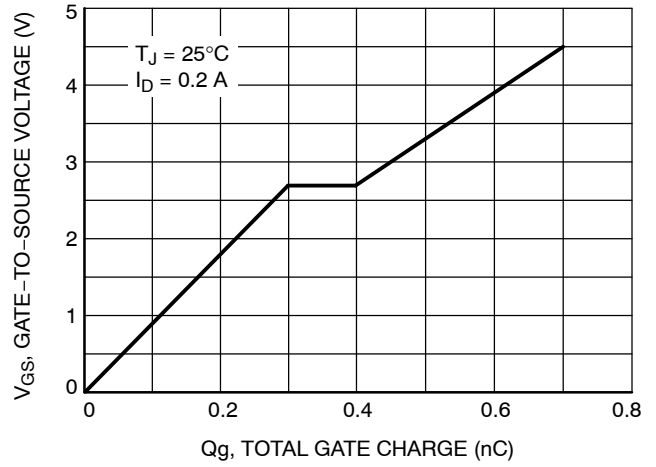


Figure 8. Gate-to-Source and Drain-to-Source Voltage vs. Total Charge

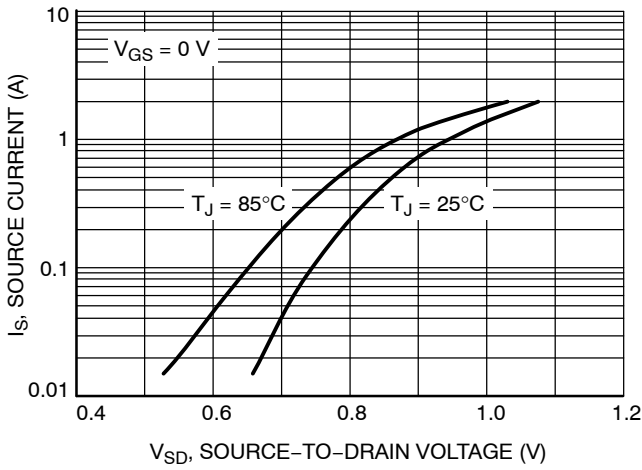


Figure 9. Diode Forward Voltage vs. Current

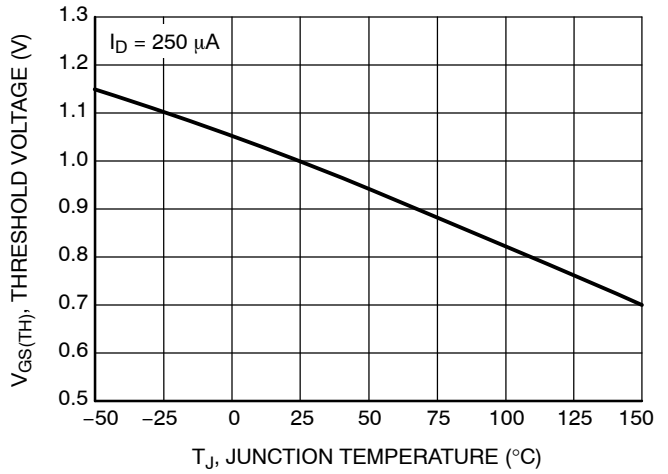


Figure 10. Threshold Voltage with Temperature

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TYPICAL CHARACTERISTICS

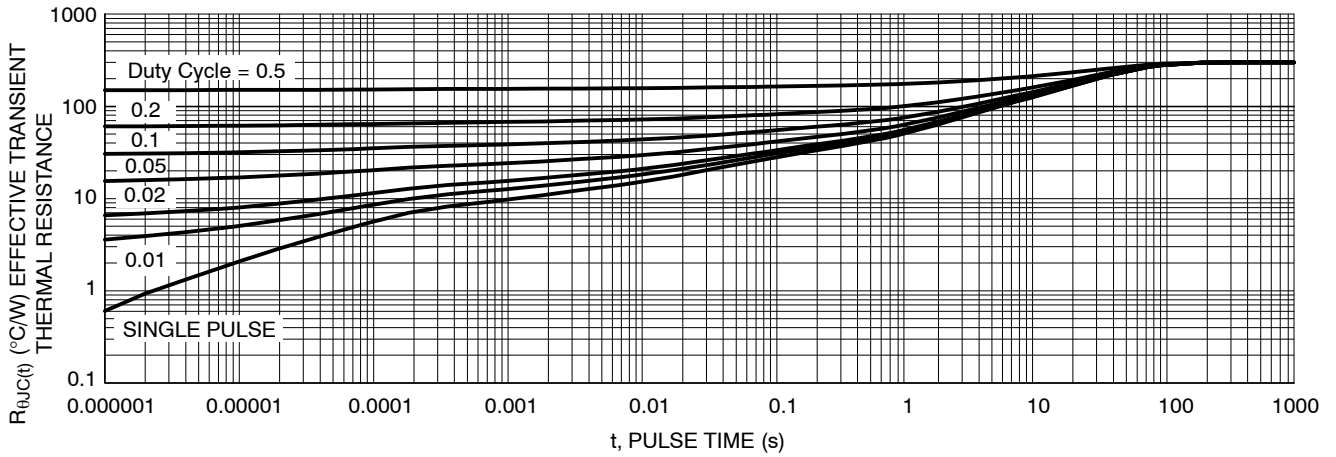


Figure 11. Thermal Response - 1 sq in pad

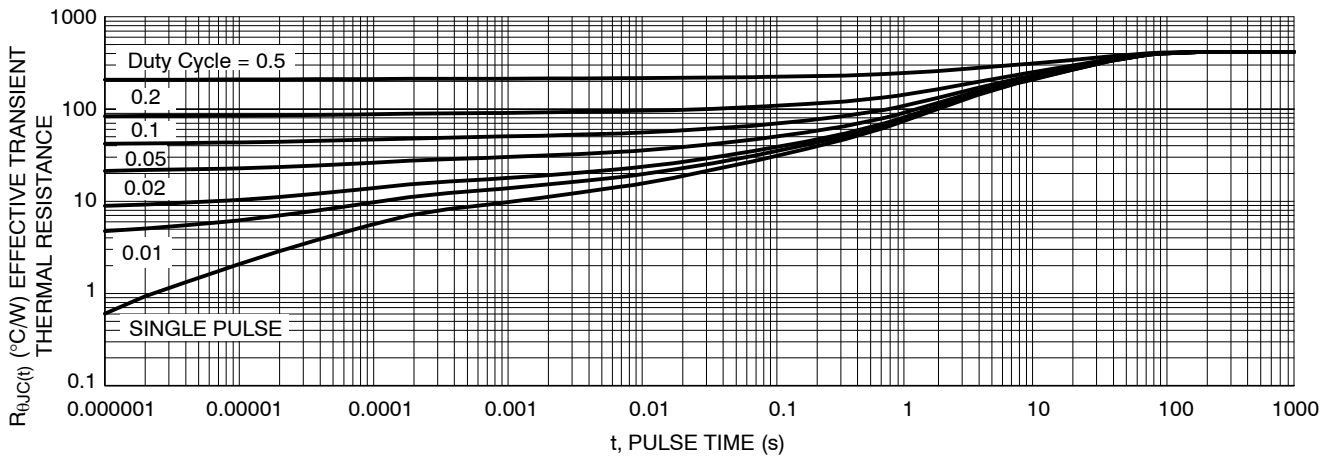
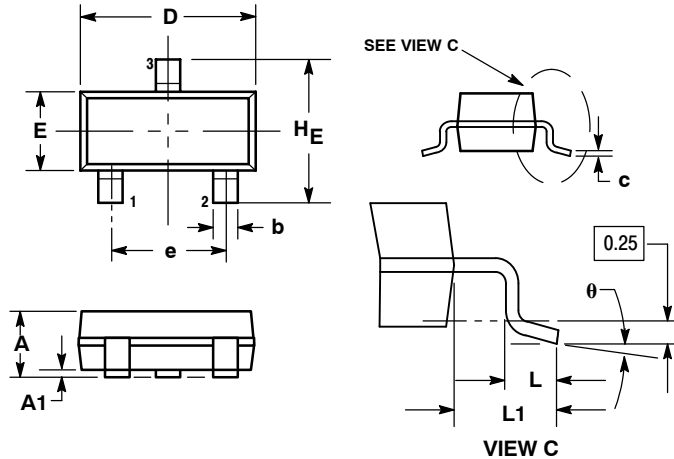


Figure 12. Thermal Response - minimum pad

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PACKAGE DIMENSIONS

SOT-23 (TO-236)
CASE 318-08
ISSUE AP

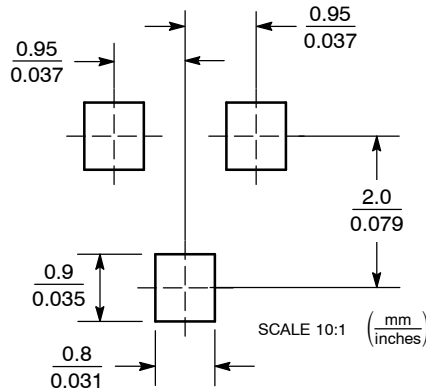


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

| DIM | MILLIMETERS | | | INCHES | | |
|-----|-------------|------|------|--------|-------|-------|
| | MIN | NOM | MAX | MIN | NOM | MAX |
| A | 0.89 | 1.00 | 1.11 | 0.035 | 0.040 | 0.044 |
| A1 | 0.01 | 0.06 | 0.10 | 0.001 | 0.002 | 0.004 |
| b | 0.37 | 0.44 | 0.50 | 0.015 | 0.018 | 0.020 |
| c | 0.09 | 0.13 | 0.18 | 0.003 | 0.005 | 0.007 |
| D | 2.80 | 2.90 | 3.04 | 0.110 | 0.114 | 0.120 |
| E | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 |
| e | 1.78 | 1.90 | 2.04 | 0.070 | 0.075 | 0.081 |
| L | 0.10 | 0.20 | 0.30 | 0.004 | 0.008 | 0.012 |
| L1 | 0.35 | 0.54 | 0.69 | 0.014 | 0.021 | 0.029 |
| HE | 2.10 | 2.40 | 2.64 | 0.083 | 0.094 | 0.104 |
| θ | 0° | --- | 10° | 0° | --- | 10° |

STYLE 21:
PIN 1. GATE
2. SOURCE
3. DRAIN

SOLDERING FOOTPRINT



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